

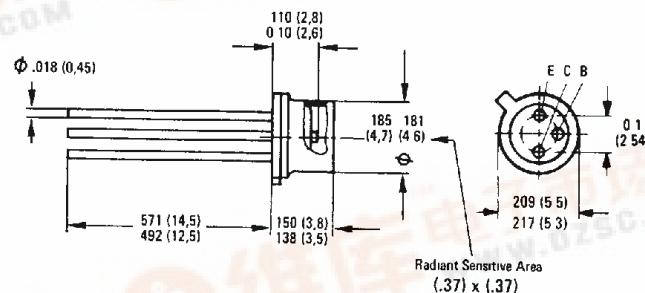
SIEMENS AKTIENGESELLSCHAFT 47E D ■ 8235605 0027523 5 ■ SIEG

**SIEMENS****SFH500****PHOTOTRANSISTOR**

T-41-61



Package Dimensions in Inches (mm)

**Maximum Ratings**

Collector emitter voltage	$V_{CEO}$	15	V
Emitter base voltage	$V_{EBO}$	7	V
Collector current	$I_C$	20	mA
Junction temperature	$T_J$	100	°C
Storage temperature	$T_S$	-55 to +100	°C
Max. soldering temperature ( $t \leq 5$ s)	$T_L$	260	°C
Power dissipation ( $T_{amb} = 25^\circ C$ )	$P_{tot}$	100	mW
Thermal resistance			
Collector junction to air	$R_{thJamb}$	600	K/W
Collector junction to case	$R_{thcase}$	250	K/W

**Characteristics ( $T_{amb} = 25^\circ C$ )**

Photocurrent ( $V_{CE} = 5$ V, $E_v = 1000$ lx) <sup>1</sup>	$I_p$	700 ( $\geq 450$ )	$\mu A$
( $V_{CE} = 5$ V, $E_v = 0.5$ mW/cm <sup>2</sup> ) <sup>2</sup>	$I_p$	185	$\mu A$
Wavelength of the max. sensitivity	$\lambda_{S\ max}$	825	nm
Quantum yield (Electrons per photon)( $\lambda = 850$ nm)	$\eta$	0.84	Electrons/Photon
Spectral sensitivity ( $\lambda = 850$ nm)	$S_\lambda$	0.56	A/W
Collector-emitter leakage current ( $V_{CE} = 10$ V, $E = 0$ )	$I_{CEO}$	20 ( $\leq 50$ )	nA
Collector-emitter saturation voltage ( $I_C = 500$ $\mu A$ , $I_B = 25$ $\mu A$ , $E = 0$ )	$V_{CEsat}$	0.8 ( $\leq 1.2$ )	V
Range of spectral sensitivity ( $S = 0.1 S_{max}$ )	$\lambda$	420 to 1100	nm
Type spectral sensitivity of the collector base photodiode	$S_A$	1.17	nA/lx
Radiant sensitive area	$A$	0.14	mm <sup>2</sup>
Rise and fall time of the photocurrent			
Rise time to 90% of the final value	$t_r$	0.25	$\mu s$
Fall time to 10% of the initial value ( $R_L = 1 k\Omega$ ) <sup>1</sup>	$t_f$		
Capacitance			
( $V_{CE} = 5$ V, $f = 1$ MHz, $E = 0$ )	$C_{CE}$	2.7	pF
( $V_{CB} = 5$ V, $f = 1$ MHz, $E = 0$ )	$C_{CB}$	5.6	pF
Cut-off frequency			
( $R_L = 50$ $\Omega$ , $V = 12$ V, $I = 5$ mA)	$f_g$	2	MHz
Current gain ( $V_{CE} = 5$ V, $I_C = 0.1$ mA)	$B$	600	—

<sup>1</sup>measured with LED  $\lambda = 950$  nm<sup>2</sup> $I_p$  (CE) = Photocurrent of the phototransistor $I_p$  (CB) = Photocurrent of the collector base photodiode

F-44-61

